

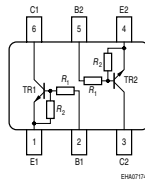
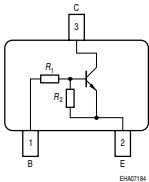
NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=4.7k\Omega$, $R_2=47k\Omega$)
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package



BCR116/F/L3
BCR116T/W

BCR116S
SEMH13



| Type | Marking | Pin Configuration | | | | | | Package |
|----------|---------|-------------------|------|------|------|------|------|----------|
| | | 1=B | 2=E | 3=C | - | - | - | |
| BCR116 | WGs | 1=B | 2=E | 3=C | - | - | - | SOT23 |
| BCR116F | WGs | 1=B | 2=E | 3=C | - | - | - | TSFP-3 |
| BCR116L3 | WG | 1=B | 2=E | 3=C | - | - | - | TSLP-3-4 |
| BCR116S | WGs | 1=E1 | 2=B1 | 3=C2 | 4=E2 | 5=B2 | 6=C1 | SOT363 |
| BCR116T | WGs | 1=B | 2=E | 3=C | - | - | - | SC75 |
| BCR116W | WGs | 1=B | 2=E | 3=C | - | - | - | SOT323 |
| SEMH13 | WG | 1=E1 | 2=B1 | 3=C2 | 4=E2 | 5=B2 | 6=C1 | SOT666 |

Maximum Ratings

| Parameter | Symbol | Value | Unit |
|---|-------------|---|------|
| Collector-emitter voltage | V_{CEO} | 50 | V |
| Collector-base voltage | V_{CBO} | 50 | |
| Emitter-base voltage | V_{EBO} | 5 | |
| Input on voltage | $V_{i(on)}$ | 15 | |
| Collector current | I_C | 100 | mA |
| Total power dissipation- BCR116, $T_S \leq 102^\circ\text{C}$ BCR116F, $T_S \leq 128^\circ\text{C}$ BCR116L3, $T_S \leq 135^\circ\text{C}$ BCR116S, $T_S \leq 115^\circ\text{C}$ BCR116T, $T_S \leq 109^\circ\text{C}$ BCR116W, $T_S \leq 124^\circ\text{C}$ SEMH13, $T_S \leq 75^\circ\text{C}$ | P_{tot} | 200 250 250 250 250 250 250 | mW |
| Junction temperature | T_j | 150 | °C |
| Storage temperature | T_{stg} | -65 ... 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|------------|------------|------|
| Junction - soldering point ¹⁾ | R_{thJS} | | K/W |
| BCR116 | | ≤ 240 | |
| BCR116F | | ≤ 90 | |
| BCR116L3 | | ≤ 60 | |
| BCR116S | | ≤ 140 | |
| BCR116T | | ≤ 165 | |
| BCR116W | | ≤ 105 | |
| SEMH13 | | ≤ 300 | |

¹For calculation of R_{thJA} please refer to Application Note Thermal Resistance

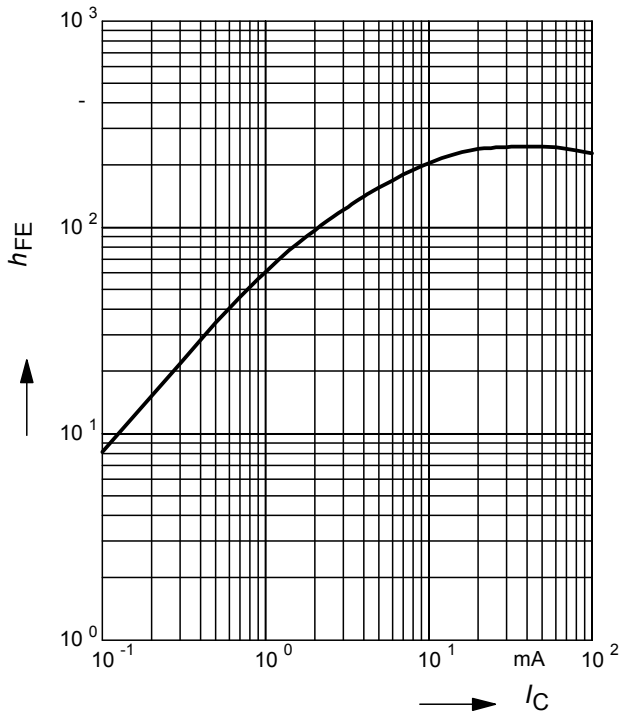
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|---|---------------|--------|------|------|------------------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$ | $V_{(BR)CEO}$ | 50 | - | - | V |
| Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$ | $V_{(BR)CBO}$ | 50 | - | - | |
| Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$ | I_{CBO} | - | - | 100 | nA |
| Emitter-base cutoff current $V_{EB} = 5 \text{ V}, I_C = 0$ | I_{EBO} | - | - | 155 | μA |
| DC current gain ¹⁾ $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$ | h_{FE} | 70 | - | - | - |
| Collector-emitter saturation voltage ¹⁾ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | V_{CEsat} | - | - | 0.3 | V |
| Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$ | $V_{i(off)}$ | 0.4 | - | 0.8 | |
| Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$ | $V_{i(on)}$ | 0.5 | - | 1.4 | |
| Input resistor | R_1 | 3.2 | 4.7 | 6.2 | $\text{k}\Omega$ |
| Resistor ratio | R_1/R_2 | 0.09 | 0.1 | 0.11 | - |
| AC Characteristics | | | | | |
| Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$ | f_T | - | 150 | - | MHz |
| Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$ | C_{cb} | - | 3 | - | pF |

¹Pulse test: $t < 300 \mu\text{s}$; $D < 2\%$

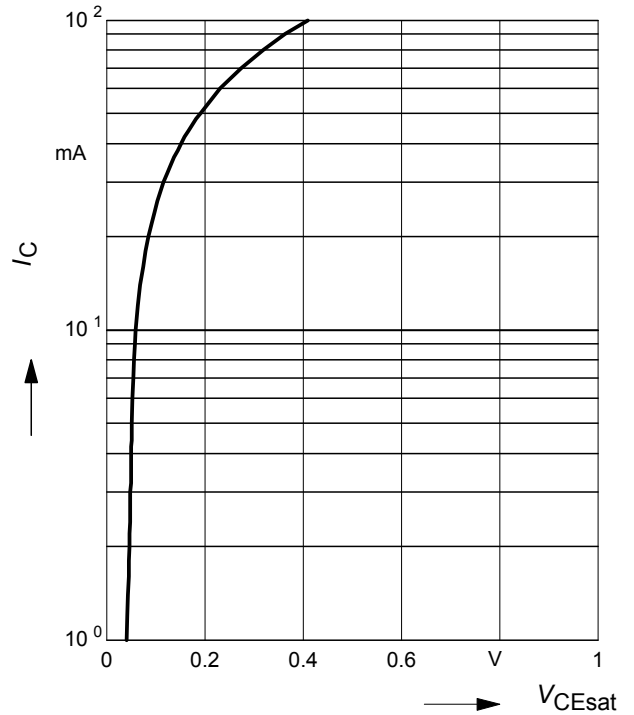
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



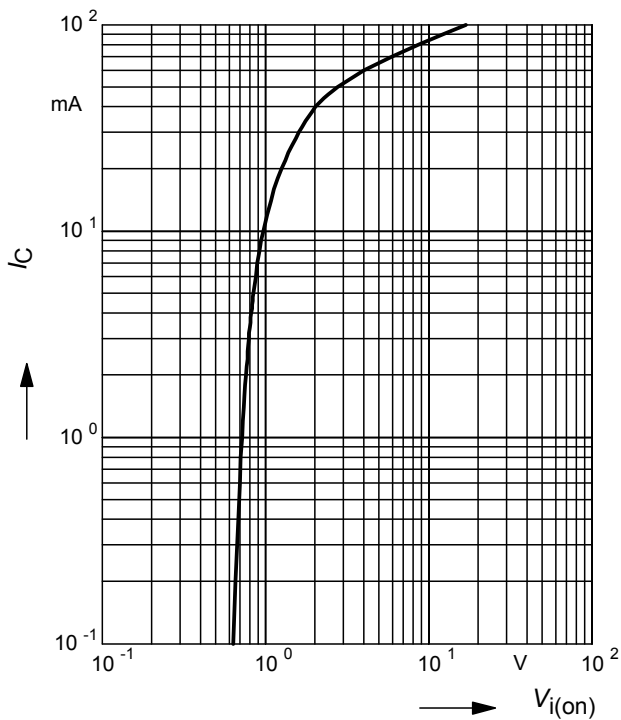
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C), h_{FE} = 20$



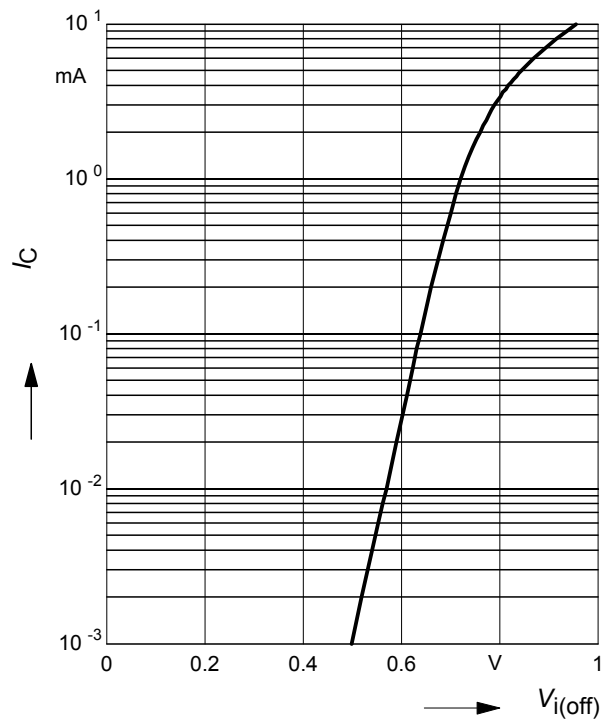
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3V$ (common emitter configuration)



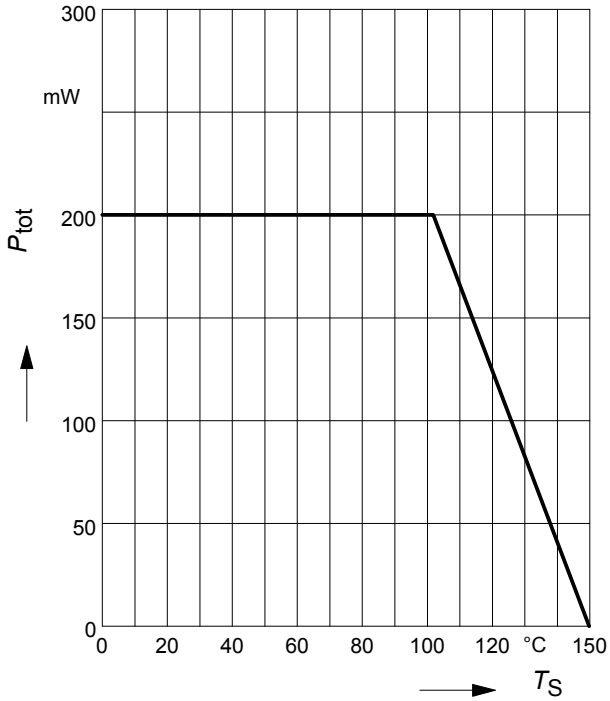
Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



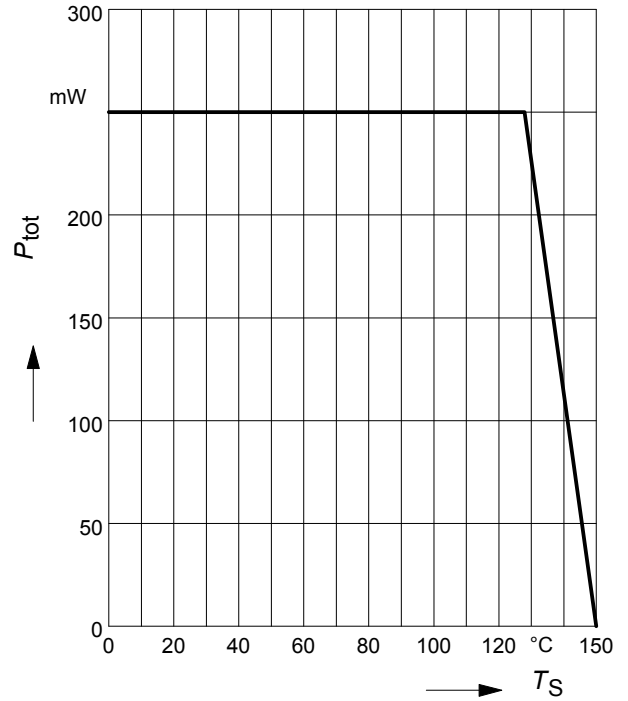
Total power dissipation $P_{tot} = f(T_S)$

BCR116



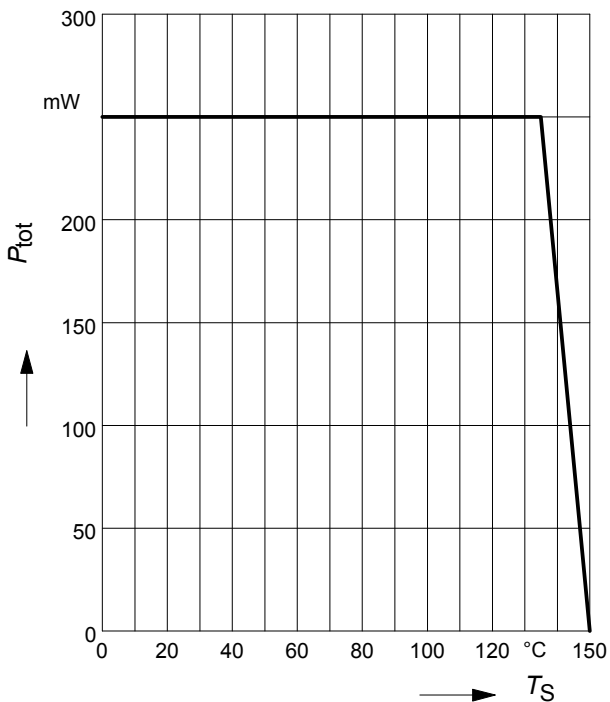
Total power dissipation $P_{tot} = f(T_S)$

BCR116F



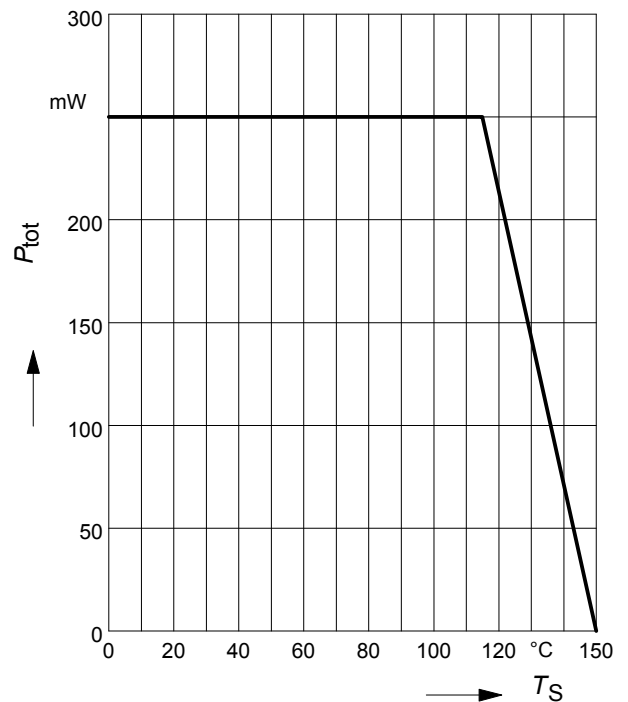
Total power dissipation $P_{tot} = f(T_S)$

BCR116L3



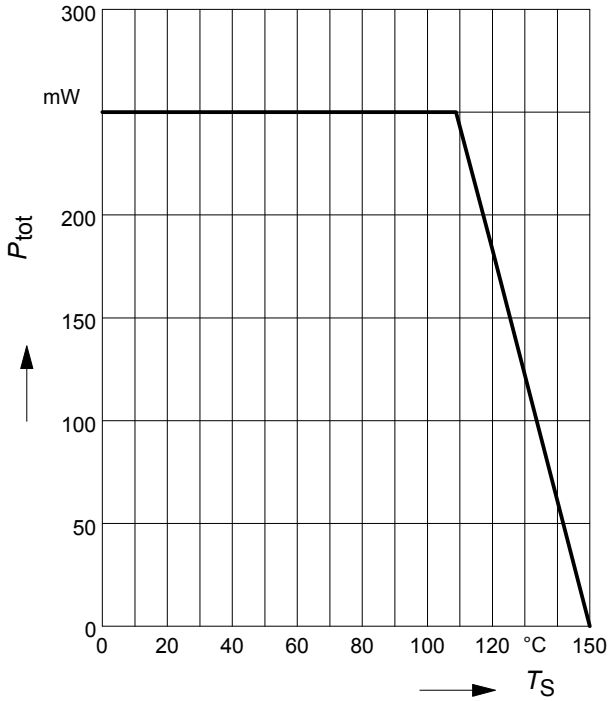
Total power dissipation $P_{tot} = f(T_S)$

BCR116S



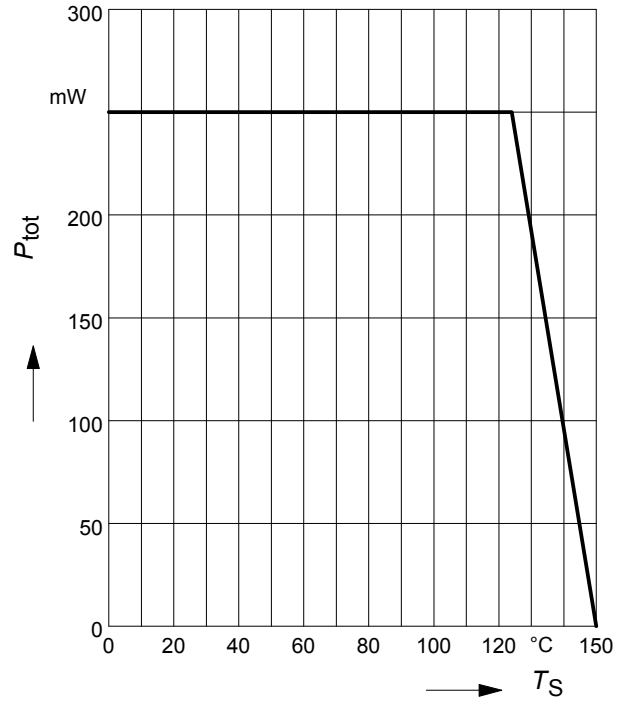
Total power dissipation $P_{tot} = f(T_S)$

BCR116T



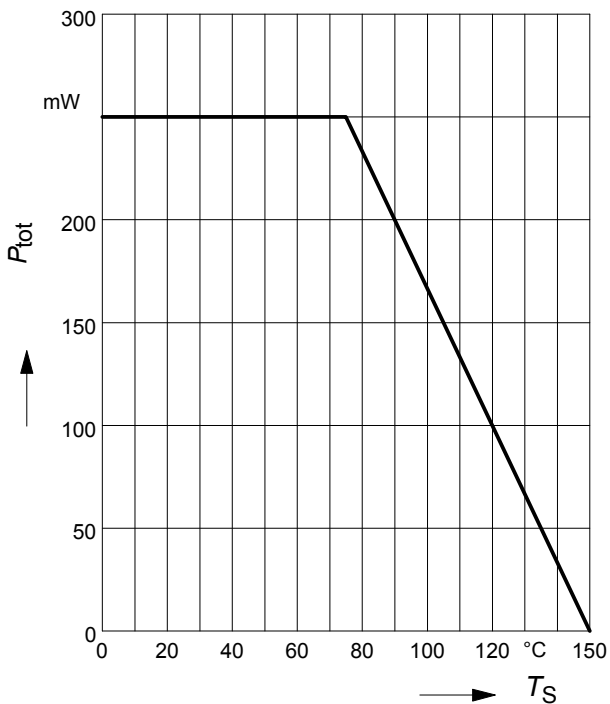
Total power dissipation $P_{tot} = f(T_S)$

BCR116W



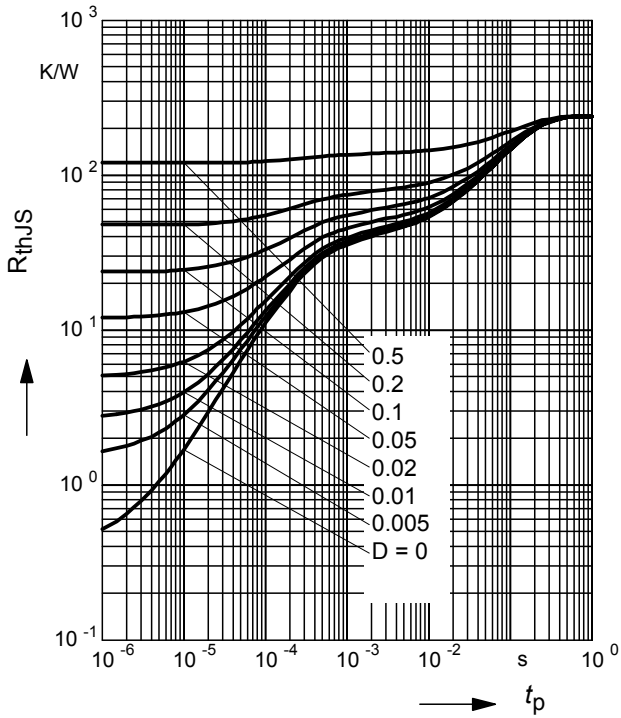
Total power dissipation $P_{tot} = f(T_S)$

SEMH13



Permissible Pulse Load $R_{thJS} = f(t_p)$

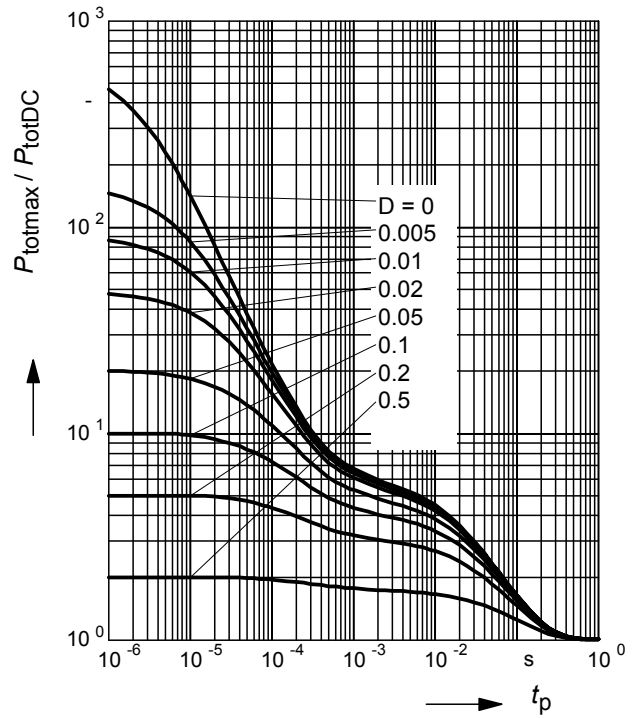
BCR116



Permissible Pulse Load

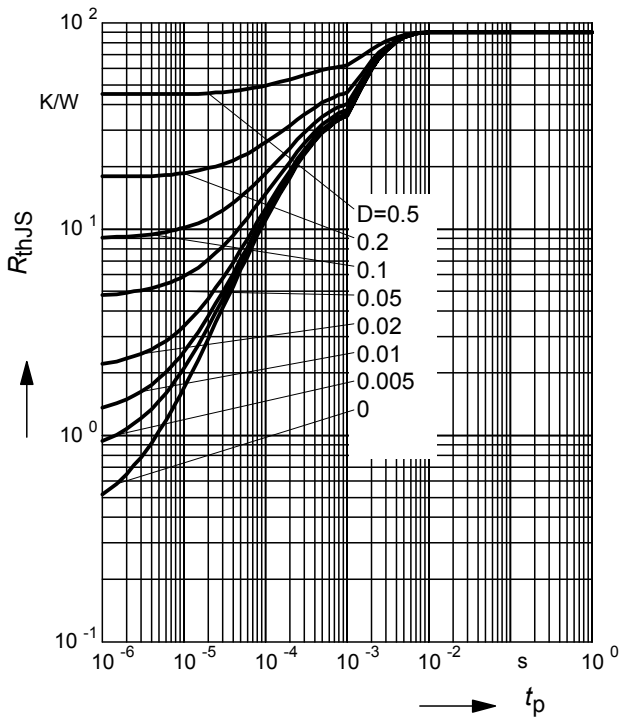
$P_{totmax}/P_{totDC} = f(t_p)$

BCR116



Permissible Puls Load $R_{thJS} = f(t_p)$

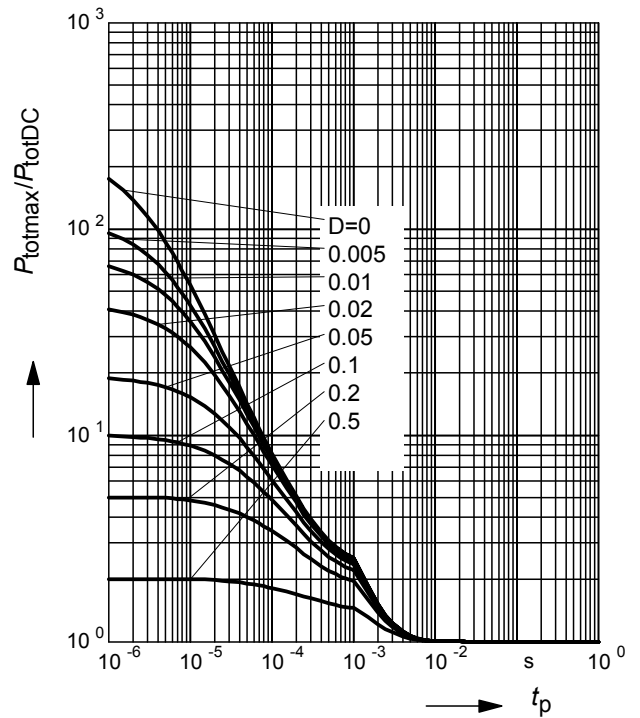
BCR116F



Permissible Pulse Load

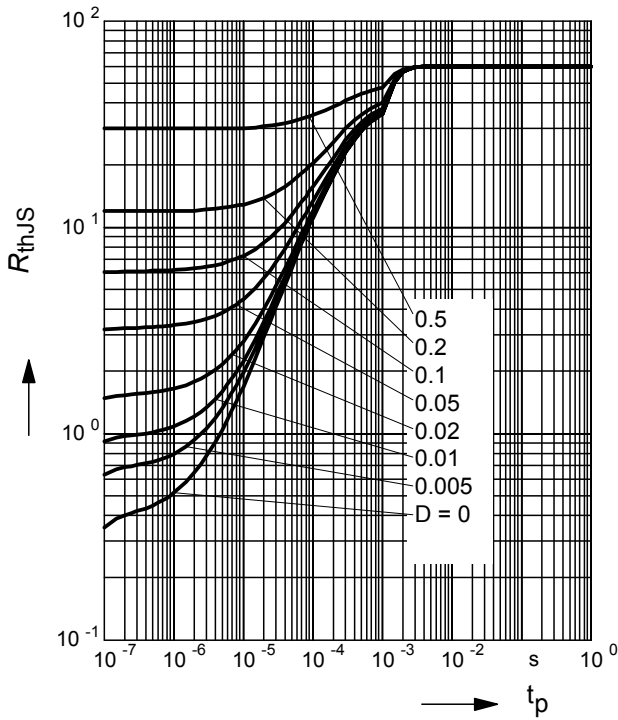
$P_{totmax}/P_{totDC} = f(t_p)$

BCR116F



Permissible Puls Load $R_{thJS} = f(t_p)$

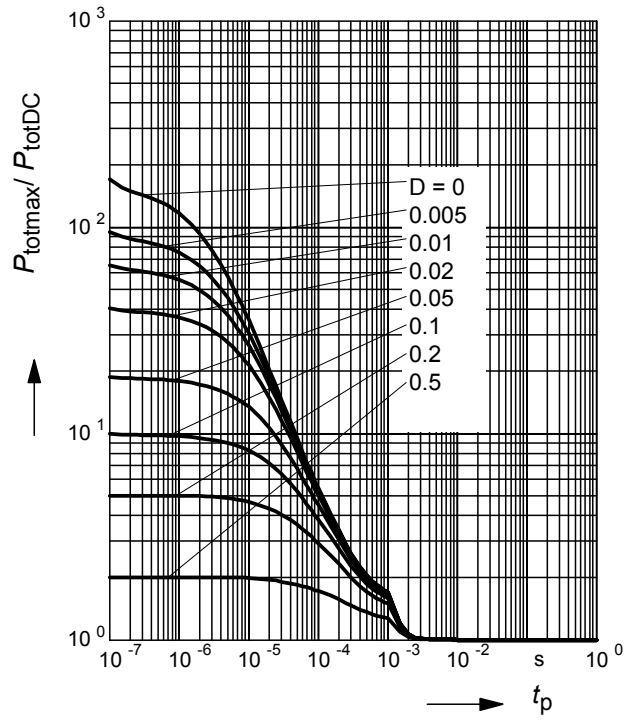
BCR116L3



Permissible Pulse Load

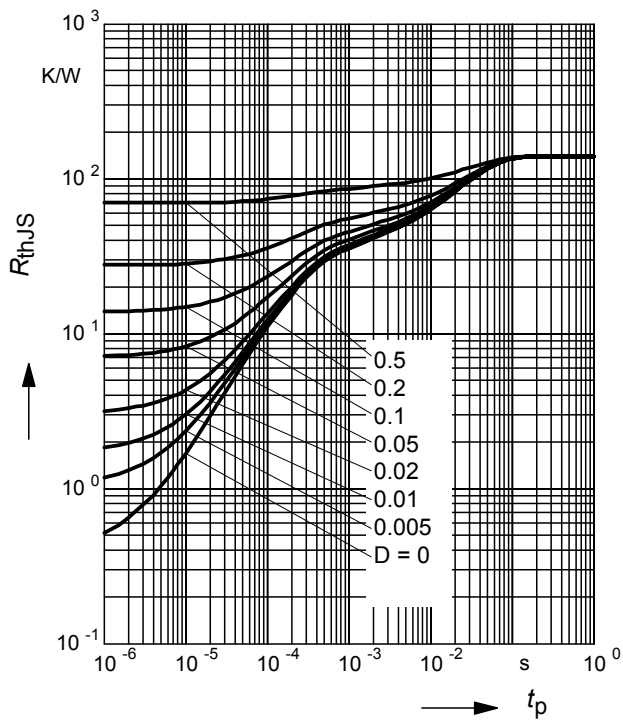
$P_{totmax}/P_{totDC} = f(t_p)$

BCR116L3



Permissible Puls Load $R_{thJS} = f(t_p)$

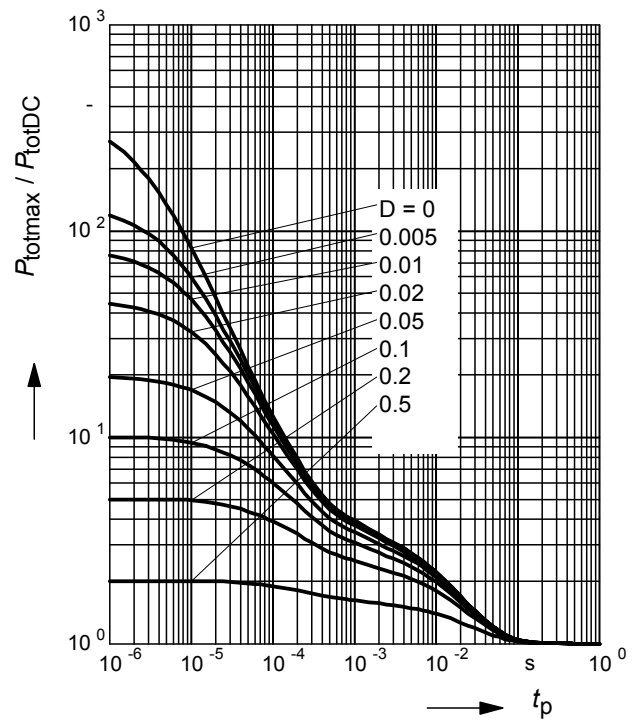
BCR116S



Permissible Pulse Load

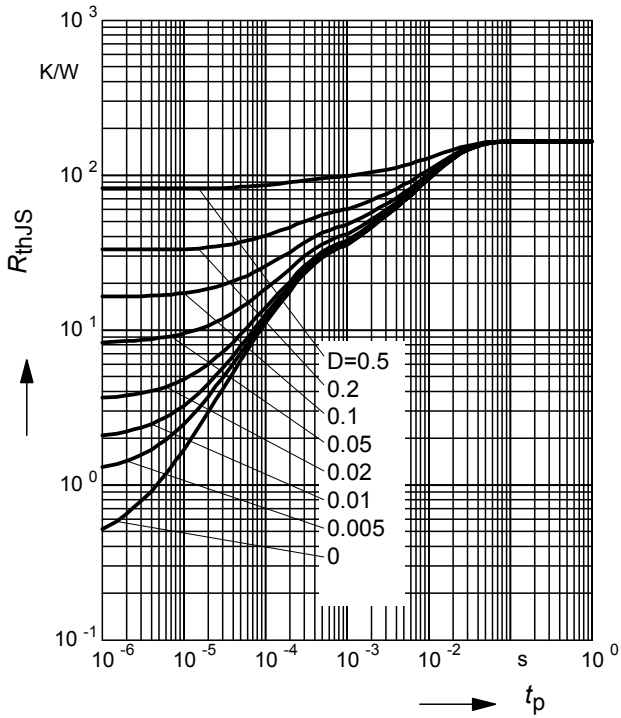
$P_{totmax}/P_{totDC} = f(t_p)$

BCR116S



Permissible Puls Load $R_{thJS} = f(t_p)$

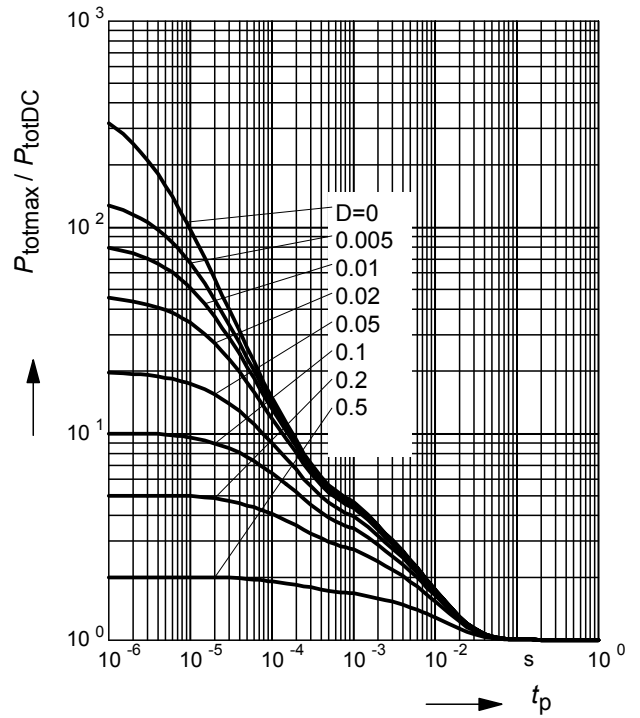
BCR116T



Permissible Pulse Load

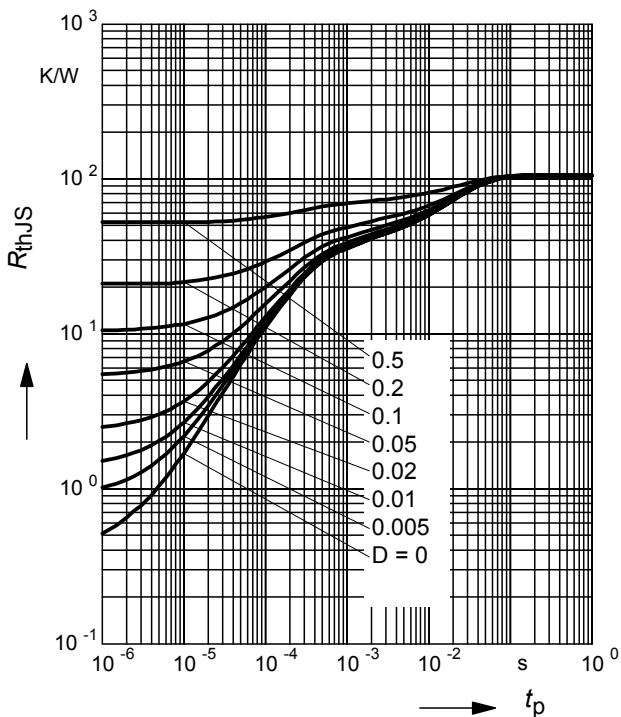
$P_{totmax}/P_{totDC} = f(t_p)$

BCR116T



Permissible Puls Load $R_{thJS} = f(t_p)$

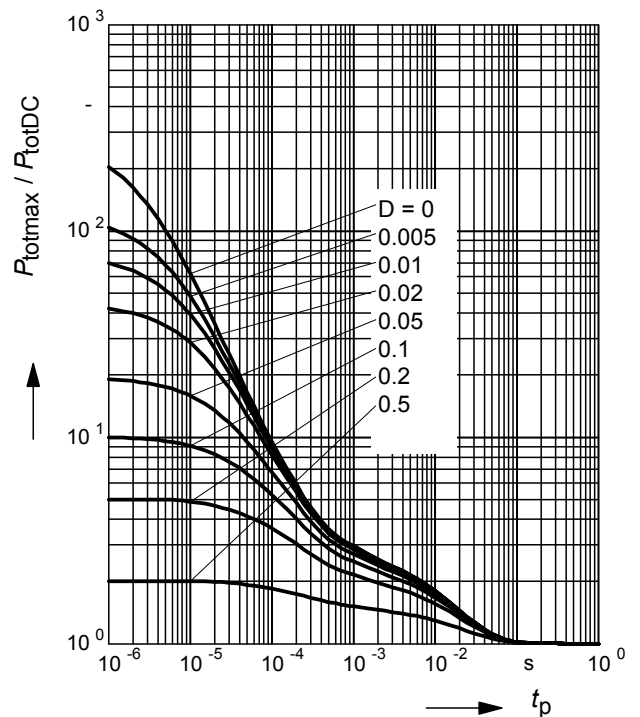
BCR116W



Permissible Pulse Load

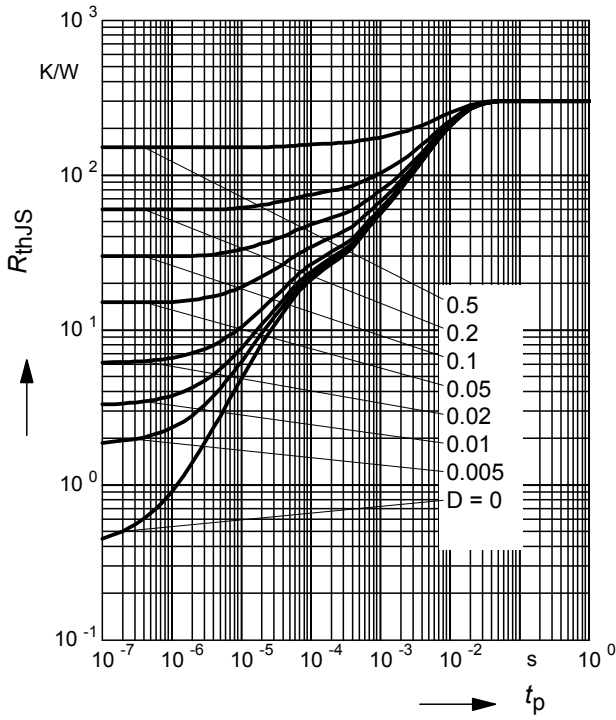
$P_{totmax}/P_{totDC} = f(t_p)$

BCR116W



Permissible Puls Load $R_{thJS} = f(t_p)$

SEMH13



Permissible Pulse Load

$P_{totmax}/P_{totDC} = f(t_p)$

SEMH13

